

DESCRIPTION

The MBR140SF is available in SOD-123 Package

- Guarding for Stress Protection
- Low Forward Voltage
- Free wheeling , and polanty protection applications

ORDERING INFORMATION

Package Type	Part Number		
SOD-123	MBR140SF		
SPQ	3,000pcs/Reel		
AiT provides all RoHS Compliant Products			

MECHANICAL DATA

Case: Molded plastic body Terminals : Plated leads solderable per MIL-STD-750,Method2026 Approx Weight:11.7mg

PIN DESCRIPTION





ABSOLUTE MAXIMUM RATINGS

@ $T_A = 25^{\circ}C$, unless otherwise specified.

Parameter	Symbol	Value	Unit	
Peak repetitive peak reverse voltage	V _{RRM}			
Working peak reverse voltage	V _{RWM}	40	V	
DC Blocking voltage	VR	2		
RMS Reverse voltage	V _{R(RMS)}	28	V	
Average rectified output current	lo	1	А	
Peak forward surge current @=8.3ms	IFSM	25	А	
Repetitive peak forward current	IFRM	625	mA	
Power dissipation	Pd	250	mW	
Thermal resistance junction to ambient	R _{0JA}	500	K/W	
Storage temperature	T _{STG}	-65 to +150	°C	
Non-Repetitive peak reverse voltage	V _{RM}	20	V	

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

ELECTRICAL CHARACTERISTICS

@ T_A = 25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min.	Max.	Unit
Reverse breakdown voltage	V _(BR)	I _R =1mA	40	-	V
Reverse voltage leakage current	I _R	V _R =20V	-	1	mA
Forward voltage	VF	I _F =1A	-	0.6	V
Diode capacitance	CD	V _R =4V,f=1.0MHz	-	120	pF



TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1. FORWARD CURRENT DERATING CURVE



Fig.3 TYPICAL INSTANTANEOUS FORWARD



Fig.5 TYPICAL JUNCTION CAPACITANCE



Fig 2. MAXMUM NON-REPETITIVE PEAK FORWARD FORWARD SURGE CURRENT



Fig.4 TYPICAL REVERSE CHARACTERISTICS



Fig.6 TYPICAL TRANSIENT THERMAL IMPEDANCE





PACKAGE INFORMATION

Dimension in SOD-123 (Unit: mm)



RECOMMAND LAND PATTERN



Symbol	Min.	Max.	
A	1.40	1.80	
В	2.55	2.85	
С	0.95	1.35	
D	0.50	0.70	
E	0.25	-	
Н	0.00	0.10	
J	-	0.15	
К	3.55	3.85	



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